

As a below named inventor, I declare that:

My residence, Post Office address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled **ELECTROPHORETIC INORGANIC POROUS MATERIAL**.

The specification of which (check only one item below):

- is attached hereto
- was filed as United States Application Serial No. on _____ and was amended on _____ (if applicable)
- was filed as PCT international application number _____, on _____, and was amended under PCT Article 19 on _____ (if applicable).

I hereby state that I have reviewed and understand the contents of the above-identified specification, including the claims, as amended by any amendment referred to above.

I acknowledge the duty to disclose information which is material to the examination of this application in accordance with Title 37, Code of Federal Regulations, § 1.56.

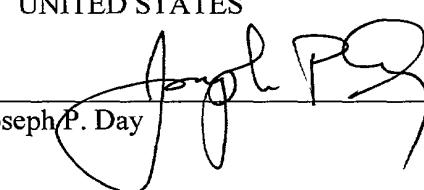
I hereby claim foreign priority benefits under Title 35, United States Code, § 119(a)-(d) or 365(b) of any foreign application(s) for patent or inventor's certificate or 365(a) of any PCT international application which designated at least one country other than the United States, listed below and have also identified below any foreign application for patent or inventor's certificate, on the same subject matter, having a filing date before that of the application on which priority is claimed:

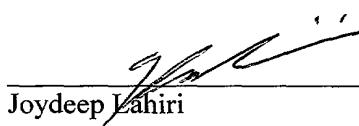
- Country:** _____ **Application No.:** _____ **Filing Date:** _____
- NONE**

I hereby claim the benefit under Title 35 United States Code § 119(e) and § 120 of any United States application(s) or 365(c) of any PCT international application designating the United States listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35 United States Code § 112, I acknowledge the duty to disclose material information as defined in Title 37 Code of Federal Regulations, § 1.56 which occurred between the filing date of the prior application and the national or PCT international filing date of this application:

- Provisional No.:** _____ **Filed:** _____ **Status:** _____
- Application No.:** _____ **Filed:** _____ **Status:** _____
- PCT Application No.:** _____ **Filed:** _____ **Status:** _____
- NONE**

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Full Name of Inventor: Joseph P. Day
Resident Address: 106 Arcadia Drive, Pacifica, California 94044
Post Office Address: same
Citizenship: UNITED STATES
DATE: 7 JAN 2002

Joseph P. Day

Full Name of Inventor: Joydeep Lahiri
Resident Address: 53 Oakwood Drive, Painted Post, New York 14870
Post Office Address: same
Citizenship: INDIA
DATE: 12/13/01

Joydeep Lahiri

Full Name of Inventor: Santona Pal
Resident Address: 53 Oakwood Drive, Painted Post, New York 14870
Post Office Address: same
Citizenship: INDIA
DATE: 12/17/01

Santona Pal

Full Name of Inventor: Mark A. Quesada
Resident Address: 3 Ambrose Drive, Horseheads, New York 14845
Post Office Address: same
Citizenship: UNITED STATES
DATE: 12/12/2001

Mark A. Quesada

DECLARATION IN ORIGINAL APPLICATION

U.S. Attorney Docket No.: WJT003-0010 (SP01-310)

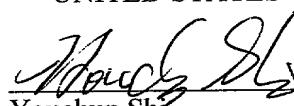
Full Name of Inventor: Youchun Shi

Resident Address: 26 Barrington Road, Horseheads, New York 14845

Post Office Address: same

Citizenship: UNITED STATES

DATE: Dec. 12, 2001


Youchun Shi